

Rectifier Diode



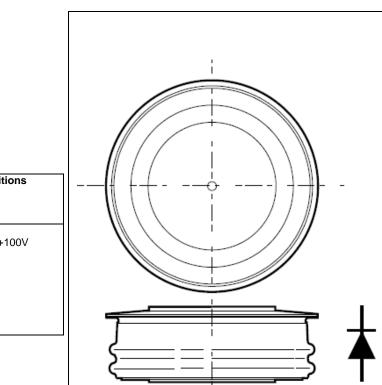
DS6007 - 1 March 2011 (LN28194)

FEATURES

- Double Side Cooling
- High Surge Capability

KEY PARAMETERS

V _{RRM}	3400V
I _{F(AV)}	850A
I _{FSM}	10800A



(See Package Details for further information)

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
DRD850D34 DRD850D32 DRD850D30 DRD850D28 DRD850D26 DRD850D24	3400 3200 3000 2800 2600 2400	V _{RSM} = V _{RRM} +100V

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD850D34 for a 3400V device

Fig. 1 Package outline



CURRENT RATINGS

T_{case} = 75°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Sid	de Cooled			
I _{F(AV)}	Mean forward current	Half wave resistive load	1020	А
I _{F(RMS)}	RMS value	-	1600	А
١ _F	Continuous (direct) on-state current	-	1440	А

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units		
Double Si	Double Side Cooled					
I _{F(AV)}	Mean forward current	Half wave resistive load	850	А		
I _{F(RMS)}	RMS value	-	1330	А		
IF	Continuous (direct) on-state current	-	1200	А		

SURGE RATINGS

Symbol	Parameter Test Conditions		Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 175^{\circ}C$	10.8	kA
l ² t	I ² t for fusing	$V_R = 0$	0.58	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.035	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.01	°C/W
T _{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-40	175	°C
T _{stg}	Storage temperature range			-40	175	°C
F _m	Clamping force			8	12	kN

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 1500A peak, T _{case} = 25°C	-	1.95	V
I _{RM}	Peak reverse current	At V _{DRM,} T _{case} = 175°C	-	50	mA
Qs	Total stored charge	I _F = 1000A, dI _{RR} /dt =10A/μs T _{case} = 175°C, V _R =100V	-	2000	μC
V _{TO}	Threshold voltage	At T _{vj} = 175°C	-	0.88	V
r _T	Slope resistance	At T _{vj} = 175°C	-	0.613	mΩ

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CURVES

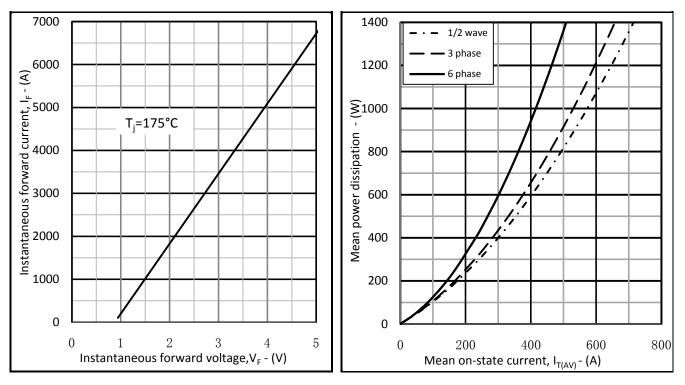
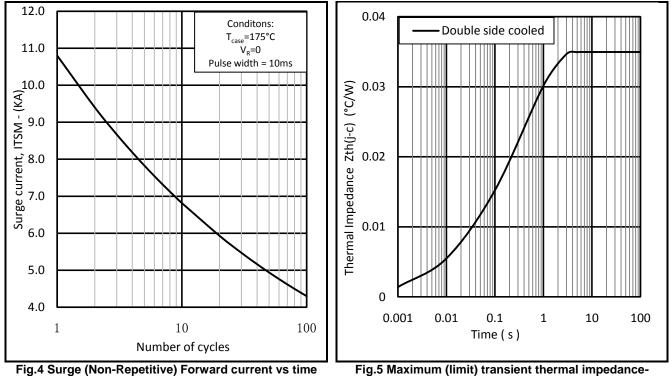


Fig.2 Maximum forward characteristics

Fig.3 Dissipation curves

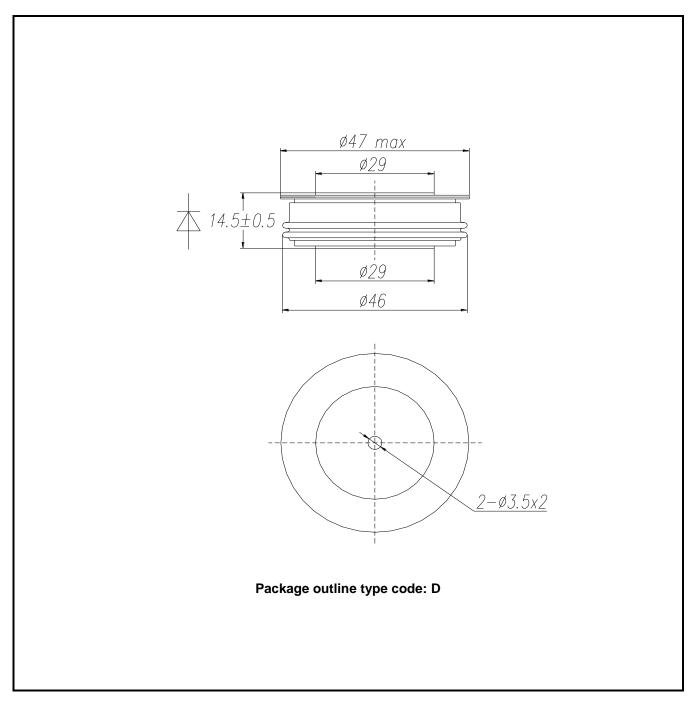


junction to case



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.



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